

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Michelle D. Griglione

Serial No.: 10/598,213

Filed: August 21, 2006

For: A BIPOLAR JUNCTION TRANSISTOR HAVING A HIGH  
GERMANIUM CONCENTRATION IN A SILICON-  
GERMANIUM LAYER AND A METHOD FOR FORMING THE  
BIPOLAR JUNCTION TRANSISTOR

Group No.: 2893

Examiner: Benjamin T. Liu

Confirmation No.: 1211

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

I hereby certify that this correspondence is being electronically filed  
with United States Patent and trademark Office on:

February 17, 2009 (Date)

Elizabeth Schumacher  
(Printed or typed name of person signing the certificate)

/Elizabeth Schumacher/  
(Signature of the person signing the certificate)

Sir:

**REQUEST FOR RECONSIDERATION UNDER 37 C.F.R. § 1.111**

In response to the Examiner's Action mailed November 17, 2008, please reconsider the  
above-identified application for the following reasons: